Novel mass air flow meter for automobile industry based on thermal flow microsensor. I. Analytical model and microsensor

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Abstract

An analytical model of the thermal flow sensor has been developed. The results of analytical model application are utilized to develop a thermal flow microsensor with optimal functional characteristics. The technology to manufacture the microsensor is described. A prototype of the microsensor suitable to be used in the mass air flow meter has been designed. The basic characteristics of the microsensor are presented.

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1. Introduction

So-called thermal flow sensors [1–3] holds a special place among modern microelectromechanical systems (MEMS), their general operation principle is based on dependency of intensity of convective heat transfer on velocity of the moving medium (fluid). The study of patents database shows an increasing interest in recent years for the development of new thermal flow microsensors design, which is based on the use of technologies to form micro- and nano-scale surface structures (see, for example, [4]). Indeed, due to fast-evolving methods of surface microstructure formation with enhanced exploitation characteristics a significant progress has been reached in the majority of critical industrial technologies as well as in microsensor manufacturing technology. In particular, miniaturization of the sensors has given new possibilities for their practical use, significantly reducing manufacturing cost and consumed electric energy.

Automobile [5–7], chemical [8] and electronic [9], medical [10] and aerospace [11] applications, air conditioning and ventilation [12] as well as other fields use thermal flow microsensors. Lately thermal flow microsensors are also used in Micro Total Analysis System (μTAS) [13] which has been significantly developed.

According to measuring principle the thermal flow sensors can be classified into three main categories: time of flight (TOF) sensors, thermal anemometers and calorimetric sensors.

The method to measure fluid velocity or fluid flow rate by using TOF sensors consists in determining the time delay of thermal pulse. The heater undergoes the pulse heating, and after some time (time of flight) temperature sensitive element located downstream the fluid flow, registers the pulse. Obviously the time of flight depends on the velocity of the fluid.

Thermal anemometers are among of the most common sensors to diagnose the fluid flow rate; they have quite a number of practical applications. In particular, the substance of one of them is to determine the dynamics of the electrically heated element that cools down as a result of heat exchange with the fluid. The heat exchange rate, in turn, depends significantly on the flow rate of the fluid. Since the electrical resistance of the most materials depends significantly on the temperature, the resistance of the material is measured to determine the temperature.

The principle of the calorimetric sensor is based on the change of the temperature field near the heated element through fluid flow. The difference of temperature between the temperature sensitive elements situated symmetrically downstream and upstream with reference to the heater is determined by the flow rate of the fluid.

Sensors based on a combination of the aforementioned measuring principles have also been developed. The calorimetric sensor is more sensitive to small flows, whereas thermal anemometers and TOF sensors are rather suitable for the diagnosis of large flows. Flow sensors based on a combination of calorimetric and TOF measuring principles are presented in works [14,15]. The method of detecting air flows in a wide range with defining the flow direction is presented in [16]: the measurement of small
flows is based on the principle of change of difference and average temperature of the two temperature sensitive elements, while measurement of larger flows is based on the thermal anemometer principle. Two electrically heated, independent, parallel hot wires over a small cavity are used to measure the direction and the absolute value of the wall shear stress in a wide range [17].

Noteworthy is a thermal anemometer microsensor for measuring liquid and gas flow rates developed in [18]. Due to low heat capacity this microsensor can also be used for the dynamic measurements in liquids, e.g. for measuring pulsations in the flow with frequencies up to several hundred Hertz.

In general, depending on the needs of the practice, thermal flow microsensors can be used to measure small gas flow rate from 0.01 ml/min [19] up to the values of a few l/min, as in [20–22]. The value of maximum gas flow rate to be measured can be significantly increased by registering a split flow, where the percentage of flow going over the sensor is known with respect to the total flow rate. In particular, this approach is implemented in Bosch HFMS5 mass air flow meter, which allows measuring the mass flow rate of air up to $10^4$ kg/h ($1.4 \times 10^4$ l/min), with relative error of less than 3%, in the tube with inner diameter of 82 mm [7].

An important characteristic of the thermal flow sensor is its sensitivity. In particular, the sensitivity of the calorimetric flow sensor is determined as follows:

$$S_k = \frac{\partial Q}{\partial \Delta T} \bigg|_{Q=0},$$

where $\Delta T$ is the difference of the temperatures of temperature sensitive elements situated symmetrically downstream and upstream of fluid flow relative to the heater, and $Q$ is mass flow rate of the fluid.

In work [23] the sensitivity of the calorimetric flow sensor was examined experimentally and numerically. It is shown that the position of temperature sensitive elements, the size of the heater and the electrical power supplied to the heater significantly affect the sensitivity of the sensor. Work [24] has shown experimentally that the sensitivity of the calorimetric flow sensor also depends on the range of measured flow rate: the lower the range, the higher the sensitivity.

In addition, sensitivity of the sensor is significantly affected by thermal insulation of temperature sensitive elements from the substrate: the better thermal insulation is, the higher is sensitivity. Currently the decrease of “parasitic” effect of the substrate is carried out by using new technological methods and materials. In particular in work [25] a method for forming a substrate with high thermal resistance based on porous silicon was suggested. Indeed, the thermal conductivity of porous silicon depending on the size of the pores and the morphology of the material is in the range between 0.1 and 2 W/m/K, which is significantly lower than thermal conductivity of polycrystalline silicon (about 170 W/m/K) that is widely used in microelectronics [26]. Besides porous silicon other materials with low thermal conductivity are used, e.g. glass (quartz or Pyrex) and silicon dioxide with thermal conductivity of each about 1–1.4 W/m/K are used.

An effective way to achieve good thermal insulation by technological means is to create an air cavity that separates thin dielectric bearing structure with the temperature sensitive elements from the massive substrate [27]. Indeed, the thermal conductivity of air which is about 0.03 W/m/K is very low value compared to the thermal conductivity of solids, and the total thermal resistance of the substrate will be high. Obviously a good thermal insulation can also significantly reduce electric power consumed by the sensor.

In this paper we will focus on the calorimetric flow microsensor, since its practical implementation can combine all three mentioned principles of measuring velocity and flow rate of the fluid. Fig. 1 illustrates the physical principle to diagnose gas flow in a channel using a calorimetric sensor. The sensor is mounted securely inside the channel either on the surface or at some distance. The measuring part of the sensor is a thin membrane that is situated on a massive substrate. Heater and temperature sensitive elements, number of which can be two or more, are enclosed inside the membrane.

From theorectic point of view to describe the heat and mass transfer process in internal gas flow is quite challenging. Indeed, the process of heat and mass transfer in channels depends on multiple factors such as the regime of the gas flow [28], the type and the size of the channel [29,30], the chemical composition of the channel’s surface and the kind of gas [31–33], temperature distribution on the surface [34], roughness of the surface [35] and the pressure ratio [36]. The heat and mass transfer is also influenced by the macroscopic and physical properties of the gas.

There is no doubt for a more accurate and precise study of the heat and mass transfer process it is preferable to use numerical methods, such as the Finite Element Method (FEM), which is free from a number of assumptions and simplifications inherent in the analytical approaches. However for better understanding of the issue and recommendations to develop design of the sensor, analytical model is also highly critical.

The analytical model of the calorimetric sensor suggested in [37] is a frequently used model. According to this model the temperature of the membrane equals to the temperature of the environment at an infinite distance from the heater. However in reality the temperature of thin membrane equals the temperature of the environment at a finite distance from the heater, where it is connected to the massive substrate.

The theoretical purpose of this study is to develop a realistic analytical model of the calorimetric flow sensor suitable for engineering calculations. The results of such calculations may be provisional data of the functional characteristics of the sensor, identification of the most crucial parts of the system, comparison of several alternative designs, system optimization and calculation of operating regimes. The practical goal of this study is to develop and design a calorimetric microsensor with functional and technological characteristics as close as possible to the optimal ones.

2. Analytical model

Let us consider a membrane in the form of a thin rectangular plate with cross section of area $S$ and perimeter $p$ (Fig. 2). The plate is assumed to be so thin and wide that the temperature at all points of the cross section can be considered equal and side effects can be neglected. This allows us to use a one-dimensional formulation of the task. Consider the plate located on the X-axis
The transfer process in the “fluid–solid” system is determining a similarity theory. Quite complicated, so it is practical to use methods of the energy transfer. Solving these equations simultaneously is determining the coefficient of heat exchange, a joint solution should be written as a system of equations for each of the flow regimes as follows [38]:

\[
Nu = \begin{cases} 
0.664Re^{1/2}Pr^{1/3} & \text{for laminar regime;} \\
0.037Re^{4/5} - APr^{1/3} & \text{for mixed regime;} \\
0.037Re^{4/5}Pr^{1/3} & \text{for turbulent regime,} 
\end{cases} 
\]

where \( A = 0.037Re^{4/5} - 0.664Re^{1/2} \), \( Re \) is critical Reynolds number.

The similarity parameters in this system of equations can be written as

\[
\begin{align*}
Nu &= H2L/\eta f; \\
Re &= UD/\eta f; \\
Pr &= \eta cf/\eta f,
\end{align*}
\]

where \( \eta f \) is the coefficient of thermal conductivity of the fluid, \( \eta f \) and \( \eta \) are their kinematic and dynamic viscosities; \( \eta cf \) is the fluid specific heat capacity at constant pressure. Note that since the membrane is inside the channel, the heat exchange coefficient depends on the hydrodynamic gas flow pattern in the channel. Therefore, it is advised to choose the diameter of cylindrical or the height of rectangular channel in determining \( Re \) Reynolds number.

The transition from laminar to turbulent flow occurs when the critical \( Re \), Reynolds number is reached. When \( Re < Re_c \), the fluid flow occurs in the laminar regime. When \( Re > Re_c \), the turbulence may be experienced. \( Re_c \) critical Reynolds number for the fluid flow in a cylindrical channel approximately equals to 2300. The fully developed turbulent regime is established at values of \( Re > 1 \times 10^4 \), and the range of \( Re \) changing from \( 2 \times 10^3 \) to \( 1 \times 10^4 \) corresponds to a mixed flow regime.

In order to not complicate excessively engineering calculations, an approximation formula to calculate the heat exchange coefficient is frequently used:

\[
H = a + bV/\sqrt{U},
\]

where \( a \) and \( b \) are the constants, determined from the condition of the best agreement with the data of certain experiment. In most practical cases the heat exchange coefficient is determined experimentally.

Using the approach suggested in [39], the solution of Eq. (2) with boundary conditions (3) is as follows:

\[
\begin{align*}
- L < x < 0: & T - T_{amb} = (T_{t=0} - T_{amb}) \exp \left( \frac{(Upcf/\eta f)}{\xi} \right) \exp \left( \frac{(Upcf/\eta f)}{\xi} \right) \exp \left( \frac{(Upcf/\eta f)}{\xi} \right) \\
- l < x \leq l: & T - T_{amb} = \frac{(T_{t=0} - T_{amb})}{\exp \left( \frac{(Upcf/\eta f)}{\xi} \right) \exp \left( \frac{(Upcf/\eta f)}{\xi} \right) \exp \left( \frac{(Upcf/\eta f)}{\xi} \right)} \\
0 < x \leq L: & T - T_{amb} = \frac{(T_{t=0} - T_{amb})}{\exp \left( \frac{(Upcf/\eta f)}{\xi} \right) \exp \left( \frac{(Upcf/\eta f)}{\xi} \right) \exp \left( \frac{(Upcf/\eta f)}{\xi} \right)} \\
\end{align*}
\]

where \( \xi = [(Upcf/2\eta f)^2 + (Hpcf/S)^2]^{1/2} \). In this solution the temperatures at the ends of the heater \( T_{t=0} \) and \( T_l \) are unknown. Let us define the temperatures at the ends of the heater, as

\[
\begin{align*}
T_1 &= T_0 + \delta T; \\
T_{t=0} &= T_0 - \delta T;
\end{align*}
\]

where \( T_0 \) is the temperature at the center of the heater with \( x = 0 \), \( \delta T > 0 \). Obviously this is a rough assumption. Nevertheless in this theoretical study we do not claim a quantitative agreement of results from our analytical model with the experimental data. It is important for us to obtain a qualitative description of the process.
From (8) it follows that the temperature at the center of the heater is given by

$$T_0-T_{amb} = \frac{(T_l-T_{amb})}{2} \exp\left(-\frac{U_{0}l}{2P}\right) + \frac{(T_{c,0}-T_{amb})}{2} \exp\left(\frac{U_{0}l}{2P}\right) + \frac{P}{2\pi hP}.$$  \hspace{1cm} (10)

Substituting our assumption (9) into this formula, we get a formula for $\Delta T$ stated as follows

$$\Delta T = \frac{(T_0-T_{amb})}{sh}\left(\frac{U_{0}l}{2P}\right) - ch\left(\frac{U_{0}l}{2P}\right) + \frac{P}{\pi hP} ch\left(\frac{U_{0}l}{2P}\right).$$  \hspace{1cm} (11)

Let us examine a frequently seen in practice case of the heating element working in the mode of constant temperature. Operating in this mode the average temperature of the heater $T_h$ at different values of fluid flow velocity $U$, is kept constant by setting the necessary electrical power $P$ supplied to the heater. To keep the calculation simple let us make another assumption that the average temperature of the heater $T_h$, determined in practice, coincides with the temperature at the center of the heating element $T_0$.

**Fig. 3** presents qualitative result of the calculation of steady-state temperature distribution in the membrane $T=T(x)$ while the sensor is in the mode of constant temperature for different gas flow velocity $U=0.01$ and $0.1$.

The temperature difference between the temperature sensitive elements located symmetrically downstream and upstream with reference to the heater is defined as

$$\Delta T = T(x_c) - T(-x_c), \quad (x_c > l).$$  \hspace{1cm} (12)

As follows from Fig. 3, in the absence of directed gas flow ($U=0$) the steady-state temperature distribution in the membrane $T=T(x)$ is presented as an even function and the temperature difference $\Delta T = 0$. The directed gas flow ($U \neq 0$) changes the temperature distribution in the membrane both in areas downstream and upstream with reference to the heater and in the heating element; and the temperature difference $\Delta T \neq 0$. The temperature difference rises with the increase of velocity of the gas flow. The figure also shows that the temperature of the temperature sensitive element located downstream close enough to the heater can exceed the average temperature of the heater.

**3. Microsensor**

The thermal flow sensor must meet fairly strict functional, technological and mechanical requirements. The important functional requirements are high level of the valid signal, rapid response and low energy consumption. The sensor must be fairly durable and reliably protected from damage and contamination. The surface of the sensor must be chemically passive. The sensor manufacturing technology must contain the maximum number of standard microelectronic production operations.

In this study the equipment used for creating the sensor is defined by requirements for manufacturing integrated micro-circuits. Manufacturing is performed in the microelectronic production in clean rooms and using standard equipment for the micro-electromechanical systems formation.

The microsensor is formed on monocrystalline silicon plate. The manufacturing technology is integral, i.e. micromachining batch of plates containing hundreds of sensors on each plate is carried out in one manufacturing process, which makes possible to achieve uniformity of the parameters of the microsensor and low manufacturing cost of a single microsensor in a mass production can be obtained. **Fig. 4** shows a plate with sensors after micromachining (planar and non-planar sides).

Initially, a raw plate undergoes hydro mechanical and chemical treatments to remove the technical contamination. At this stage using the method of double-sided lithography two-way labels are formed. Labels are used to combine topologies of opposite sides of the plate in the process of photolithography in subsequent operations.

At the next stage the oxidation of the plate up to 1.2–2.0 $\mu$m in thickness on both sides is performed in order to obtain the etching mask membrane and insulation of the electrical circuit from the substrate. Afterwards a silicon nitride layer around 0.15 $\mu$m thick is applied to the surface of the planar side of the plate.

The following layer applied on a planar side of the plate is a doped polycrystalline silicon in order to form electric conductors, resistance of which depends on the temperature. For this purpose by gas-phase method the surface of silicon nitride is coated with 1 $\mu$m thick polycrystalline silicon; then polysilicon layer is alloyed with a dope. Alloying is performed according to regime which ensures the highest temperature coefficient resistance (TCR) with a sufficiently high level of linear dependency between resistance and temperature. The configuration of heating and four temperature sensitive resistors located in the membrane, as well as one resistor on the edge of the sensor used for measuring air temperature, are formed in this layer. The conductors system in order to put this configuration in the external circuitry for recording and processing the valid signal is also formed at this stage.

![Fig. 3. Steady-state temperature distribution in the membrane $T=T(x)$, while the calorimetric flow sensor is in the mode of constant temperature for different gas flow velocity $U=0$ (a); 0.01 (b) and 0.1 (c).](image)

![Fig. 4. The silicon plate after micromachining. The planar and non-planar sides.](image)
The electrical circuit in the polycrystalline silicon layer is formed by using the photolithography method. Fig. 5 shows the location of the heater (in the center) and four temperature sensitive resistors in the membrane. The sizes of the heater and the temperature sensitive resistors, as well as their location in the membrane, are determined on the basis of preliminary theoretical calculations according to developed analytical model and features of the available technology and equipment.

After this 0.2 μm thick silicon nitride is deposited on the formed surface of the planar side of the plate. Thus, the conductive layer is “packed” into impermeable cover of silicon nitride and is not under the threat of chemical effect of the environment and the technological reagents.

At the final stage the plate undergoes micromachining (Fig. 4). With the use of previously formed labels a photolithography process is carried out in order to obtain the topology of the plate’s surface as a whole, in particular lines for scribing and membranes etching masks are formed. In the membrane area on the non-planar side of the plate the monocrystalline silicon is etched to 10–20 μm thickness, which is sufficient to provide mechanical strength to carry out further operations.

At this stage bonding areas are formed by vacuum deposition of aluminum to subsequently put microsensor in external circuitry. To divide into individual crystals, on each of which a separate microsensor is formed, diamond scribing of the plate is performed.

The final step is the complete removal of the monocrystal silicon in membrane area to reduce the “parasitic” effect of the substrate and to remove the mechanical stresses conditioned by differences in the temperature of various materials' films formations. Thus, the bearing element of the membrane is nitride and oxide of silicon. As a result the total thickness of the membrane with circuitry located inside is less than 2 μm.

Fig. 6 presents a microsensor in a testing case. The figure shows that the membrane is so thin that the gilded cover underneath it can be clearly seen. According to the measurements a typical resistance of the temperature sensitive resistors under normal climate conditions is: 498 Ω for the heater; 4469 Ω for the first resistor (Fig. 5, left to right), 3399, 3383 and 4452 Ω for the second, third and fourth resistors, respectively. The resistors’ temperature coefficient of resistance (TCR) α is $1.3 \times 10^{-4} \, (K^{-1})$.

4. Conclusion

The main results of the performed study are the analytical model of the calorimetric flow sensor and a prototype of microsensor for mass air flow meter.

The developed analytical model of the sensor is suitable for engineering calculations. The design and manufacturing technology of the microsensor enable mass production, subsequent device assembly and reliable operation as well. The obtained results are important for development, production and optimization of the thermal flow microsensors. The next stage of the research is the development and design of the mass air flow meter for automobile industry based on the thermal flow microsensor presented in this paper.

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Appendix A. Supporting information

Supplementary data associated with this article can be found in the online version at http://dx.doi.org/10.1016/j.flowmeasinst.2013.01.006.
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